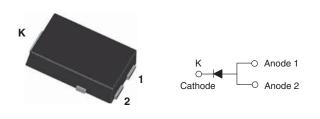
Vishay Semiconductors





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TO-277A (SMPC)

PRODUCT SUMMARY					
Package	TO-277A (SMPC)				
I _{F(AV)}	4 A				
V _R	100 V				
V _F at I _F	0.93 V				
t _{rr} (typ.)	27 ns				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, piezo-injection, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V _{RRM}		100	V			
Average rectified forward current	I _{F(AV)}	T _{Sp} = 165 °C	4	А			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	130	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	100	-	-	
	V	$I_F = 4 A$	-	0.86	0.93	V
Forward voltage	V _F	I _F = 4 A, T _J = 125 °C	-	0.73	0.79	
		V _R = V _R rated	-	-	2	
Reverse leakage current I _R		T _J = 125 °C, V _R = V _R rated	-	1	10	μA
Junction capacitance	CT	V _R = 100 V	-	24	-	pF

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RoHS

COMPLIANT

HALOGEN

FREE



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \ dI_F/dt = 50 \text{ A}$	4/μs, V _R = 30 V	-	27	-		
Povoroo rocovoru timo	+	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	-	25		
neverse recovery lime	Reverse recovery time t _{rr}	T _J = 25 °C		-	20	-	ns	
		T _J = 125 °C		-	31	-		
Dook roooyon, ourront		T _J = 25 °C	$I_F = 4 A$	-	2.2	-	Α	
Peak recovery current I _{RRM}	T _J = 125 °C	dl _F /dt = 200 A/µs V _R = 160 V	-	4.4	-			
Reverse recovery charge Q _{rr}	T _J = 25 °C		-	22	-	nC		
	T _J = 125 °C		-	70	-	10		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to solder pad	R _{thJ-Sp}		-	2.2	3	°C/W
Approximate weight				0.1		g
				0.0035		oz.
Marking device		Case style TO-277A (SMPC)		JE	H1	

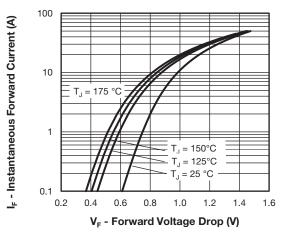


Fig. 1 - Typical Forward Voltage Drop Characteristics

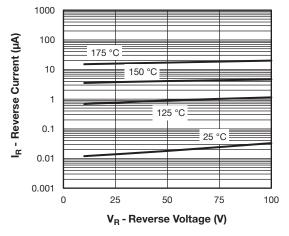
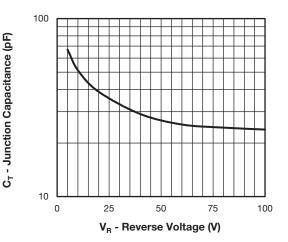


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

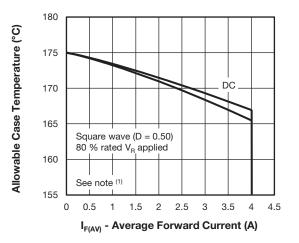
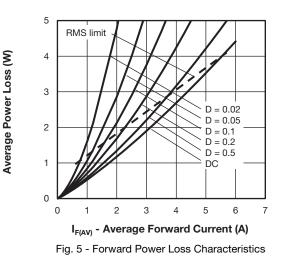


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current



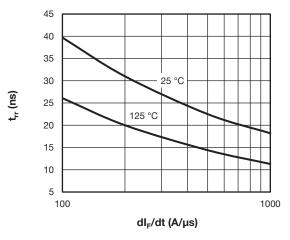


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

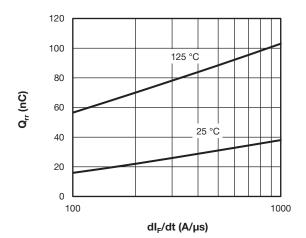


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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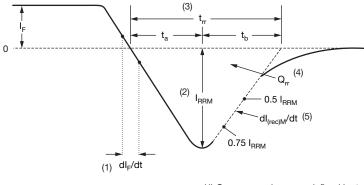
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VS-4ESH01HM3

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- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(4) ${\rm Q}_{\rm rr}$ - area under curve defined by ${\rm t}_{\rm rr}$ and ${\rm I}_{\rm RBM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	VS-	4	Е	s	Н	01	Н	М3
		2	3	4	5	6	7	8
	1		-	niconduo	•	oduct		
	2 · 3 ·			ng (4 = 4 iguratior	,			
	_	E =	single c	liode				
	4 ·			package	9			
	5 -		cess typ hyperfa	e, ist recov	very			
	6	Volt	age coo	de (01 =	100 V)			
	7 ·	H =	AEC-Q	101 qua	lified			
	8	M3	= halog	en-free,	RoHS-	complia	nt, and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-4ESH01HM3/86A	1500	1500	7" diameter plastic tape and reel				
VS-4ESH01HM3/87A	6500	6500	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95570					
Part marking information	www.vishay.com/doc?95565				
Packaging information	www.vishay.com/doc?88869				

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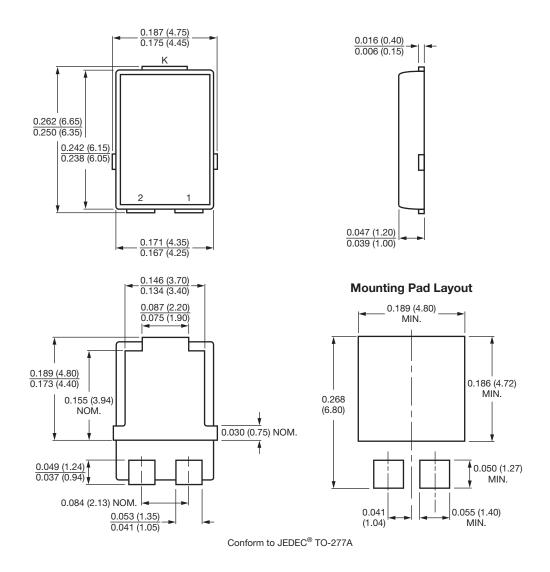
Outline Dimensions





TO-277A (SMPC)

DIMENSIONS in inches (millimeters)





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